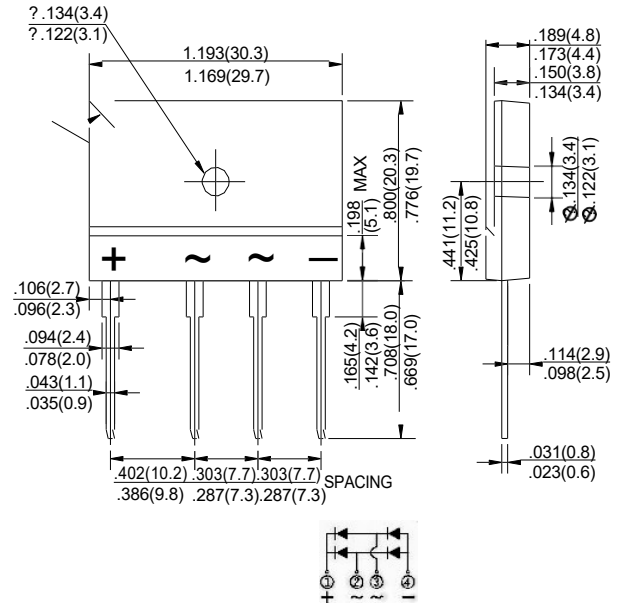


SILICON BRIDGE RECTIFIERS

Features

- ◆ Rating to 1000V PRV
- ◆ Ideal for printed circuit board
- ◆ Reliable low cost construction utilizing molded plastic
- ◆ technique Plastic material has U/L lammability classification 94V-0
- ◆ Low forward voltage drop,high current capability

GBJ



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	GBJ50005	GBJ5001	GBJ5002	GBJ5004	GBJ5006	GBJ5008	GBJ5010	UNITS
Marking Code									
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward (with heatsink NOTE 2) Rectified current @ $T_c=100^{\circ}C$ (without heatsink)	I_{AV}	50.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	400							A
Rating for Fusing ($t < 8.3ms$)	I^2t	664							A ² s
Maximum forward voltage at 25A DC	V_F	1.1							V
Maximum DC reverse current $T_A=25^{\circ}C$ at rated DC blocking voltage $T_A=125^{\circ}C$	I_R	10							μA
		0.5							mA
Typical Junction Capacitance (Note 1)	C_J	85							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	0.6							$^{\circ}C/W$
Operating junction temperature range	T_J	-55 to +150							$^{\circ}C$
storage temperature range	T_{STG}	-55 to +150							$^{\circ}C$

NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.

3. The typical data above is for reference only.